



L272 / L272A

Dual Power Operational Amplifier

Features

- Output Current up to 0.7 A
- Operates at Low Voltage ($V_S(\text{MIN}) = 4 \text{ V}$)
- Low Saturation Voltage ($I_P = 0.5 \text{ A}$, $V_O = 1.5 \text{ V}$)
- Thermal Shutdown ($T_{SD} = 160^\circ\text{C}$)
- Ground-Compatible Inputs
- Large Common Mode & Differential Mode Range

Applications

- Servo Amplifier
- Power Supply
- Compact Disc
- VCR
- Monitor

Description

The L272 and L272A are high-power dual operational amplifiers provided in a MDIP 8-lead package. The operational amplifier is designed for low-impedance loads and delivers output current up to 0.7 A. The L272A offers tighter specifications for input bias current, input offset voltage, and input offset current. The L272 and L272A can be used in a wide range of applications, including power supply, VCR, monitor, servo amplifier, compact disc, etc.



Ordering Information

Part Number	Operating Temperature Range	Top Mark	Package	Packing Method
L272M	-40 to +85°C	L272M	MDIP 8L	Rail
L272AM		L272AM	MDIP 8L	Rail

Block Diagram

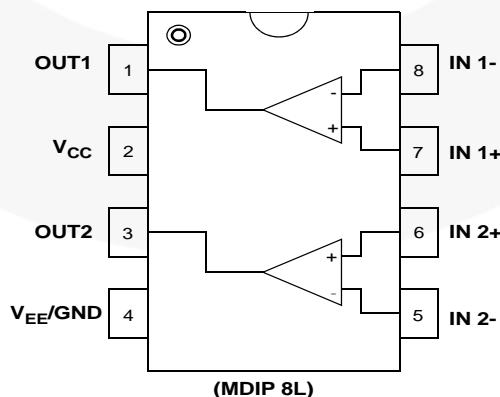


Figure 1. Block Diagram

Pin Descriptions

Pin Number	Name	Description
1	OUTPUT1	Amplifier Output 1
2	VCC	Positive Supply Voltage
3	OUTPUT2	Amplifier Output 2
4	VEE/GND	Negative Supply Voltage (GND)
5	INPUT-2	Amplifier Negative Input 2
6	INPUT+2	Amplifier Positive Input 2
7	INPUT+1	Amplifier Positive Input 1
8	INPUT-1	Amplifier Negative Input 1

Absolute Maximum Ratings⁽¹⁾

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	40	V
V_I	Input Voltage	V_S	V
$V_{I(DIFF)}$	Differential Input Voltage	$\pm V_S$	V
I_O	DC Output Current	0.7	A
I_P	Peak Output Current (Non-Repetitive)	1	A
T_{OP}	Operating Temperature Range	-40 to 85	$^\circ\text{C}$
T_{STG}, T_J	Storage and Junction Temperature Range	-40 to 150	$^\circ\text{C}$

Note:

1. The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings.

Thermal Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
P_D	Total Power Dissipation ($T_A = 50^\circ\text{C}$)	1	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	100	$^\circ\text{C}/\text{W}$

Electrical Characteristics (L272)

$V_{CC} = +12\text{ V}$, $V_{EE} = -12\text{ V}$; Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_S	Supply Voltage ($V_{CC} - V_{EE}$)		4		28	V
I_S	Supply Current	$V_O = V_{CC}/2$, $V_{CC} = 24\text{ V}$, $V_{EE} = 0\text{ V}$		8.0	12.0	mA
		$V_O = V_{CC}/2$, $V_{CC} = 12\text{ V}$, $V_{EE} = 0\text{ V}$		7.5	11.0	
I_{BIAS}	Input Bias Current			0.3	2.5	μA
V_{IO}	Input Offset Voltage			15	60	mV
I_{IO}	Input Offset Current			50	250	nA
SR	Slew Rate	$V_{IN} = 1\text{V}_{PP}$, Unit Gain		1		$\text{V}/\mu\text{s}$
GBW	Gain-Bandwidth Product			350		kHz
R_I	Input Resistance		500			$\text{k}\Omega$
G_V	Large-Signal Voltage Gain	$V_{O(pp)} = \pm 10\text{ V}$	65	75		dB
e_N	Input Noise Voltage	$B = 20\text{ kHz}$		10		μV
I_N	Input Noise Current	$B = 20\text{ kHz}$		200		pA
CMRR	Common Mode Rejection Ratio		60	75		dB
PSRR	Supply Voltage Rejection Ratio	$V_{CC} = +15\text{ V}$, $V_{EE} = -15\text{ V}$ $V_{CC} = +5\text{ V}$, $V_{EE} = -5\text{ V}$	54	62		dB
V_O	Output Voltage Swing	$V_{CC} = 24\text{ V}$, $V_{EE} = 0\text{ V}$, $I_P = 0.1\text{ A}$	21.0	23.0		V
		$V_{CC} = 24\text{ V}$, $V_{EE} = 0\text{ V}$, $I_P = 0.5\text{ A}$	21.0	22.5		
C_S	Channel Separation	$f = 1\text{ kHz}$, $R_L = 10\text{ }\Omega$, $G_V = 30\text{ dB}$		60		dB
THD	Total Harmonic Distortion	$f = 1\text{ kHz}$, $G_V = 1\text{ dB}$, $R_L = \infty$		0.5		%
TSD	Thermal Shutdown Temperature ⁽²⁾			160		$^\circ\text{C}$

Note:

2. Guaranteed by design; not 100% tested in production.

Electrical Characteristics (L272A)

$V_{CC} = +12\text{ V}$, $V_{EE} = -12\text{ V}$; Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_S	Supply Voltage ($V_{CC} - V_{EE}$)		4		28	V
I_S	Supply Current	$V_O = V_{CC}/2$ $V_{CC} = 24\text{ V}$, $V_{EE} = 0\text{ V}$		8.0	12.0	mA
		$V_O = V_{CC}/2$, $V_{CC} = 12\text{ V}$, $V_{EE} = 0\text{ V}$		7.5	11.0	mA
I_{BIAS}	Input Bias Current			0.1	1.0	μA
V_{IO}	Input Offset Voltage			7	30	mV
I_{IO}	Input Offset Current			20	100	nA
SR	Slew Rate	$V_{IN} = 1\text{V}_{PP}$, Unit Gain		1		$\text{V}/\mu\text{s}$
GBW	Gain-Bandwidth Product			350		kHz
R_I	Input Resistance		500			$\text{k}\Omega$
G_V	Large-Signal Voltage Gain	$V_{O(pp)} = \pm 10\text{ V}$	65	75		dB
e_N	Input Noise Voltage	$B = 20\text{ kHz}$		10		μV
I_N	Input Noise Current	$B = 20\text{ kHz}$		200		pA
CMRR	Common Mode Rejection Ratio		60	75		dB
PSRR	Supply Voltage Rejection Ratio	$V_{CC} = +15\text{ V}$, $V_{EE} = -15\text{ V}$ $V_{CC} = +5\text{ V}$, $V_{EE} = -5\text{ V}$	54	62		dB
V_O	Output Voltage Swing	$V_{CC} = 24\text{ V}$, $V_{EE} = 0\text{ V}$, $I_p = 0.1\text{ A}$	21.0	23.0		V
		$V_{CC} = 24\text{ V}$, $V_{EE} = 0\text{ V}$, $I_p = 0.5\text{ A}$	21.0	22.5		V
C_S	Channel Separation	$f = 1\text{ kHz}$, $R_L = 10\ \Omega$, $G_V = 30\text{ dB}$		60		dB
THD	Total Harmonic Distortion	$f = 1\text{ kHz}$, $G_V = 1\text{ dB}$, $R_L = \infty$		0.5		%
TSD	Thermal Shutdown Temperature ⁽³⁾			160		$^\circ\text{C}$

Note:

3. Guaranteed by design; not 100% tested in production.

Typical Performance Characteristics

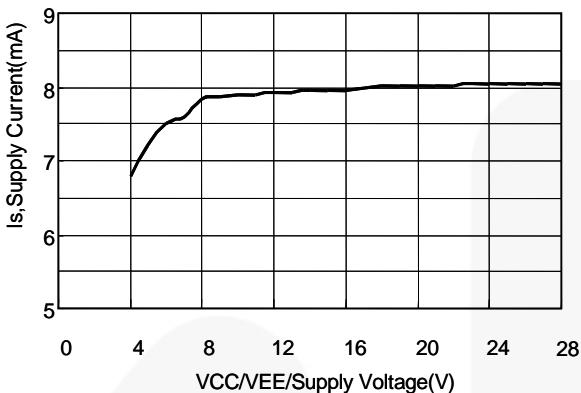


Figure 2. Supply Voltage vs. Supply Current with No Load

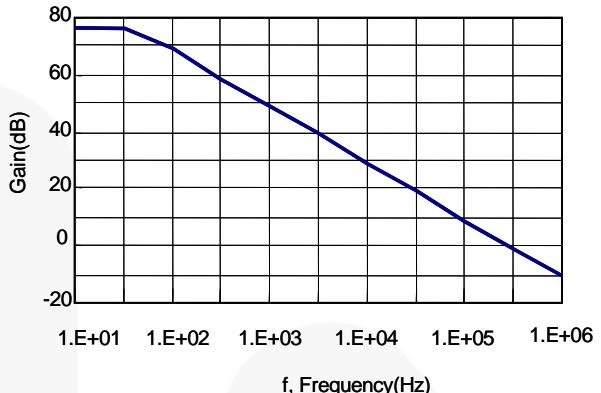


Figure 3. Open-Loop Voltage Gain

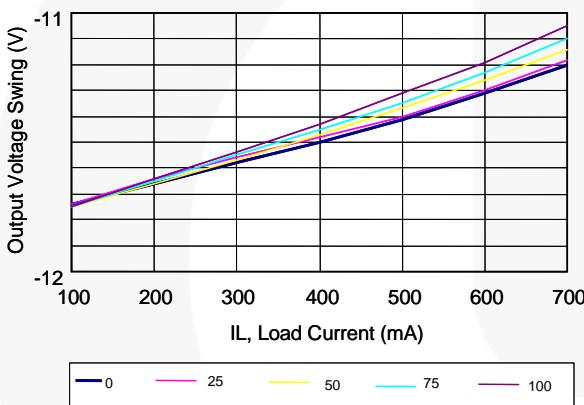


Figure 4. Output Voltage Swing vs. Load Current

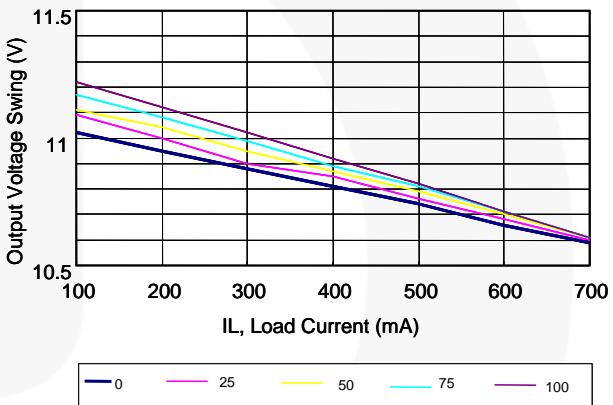


Figure 5. Output Voltage Swing vs. Load Current

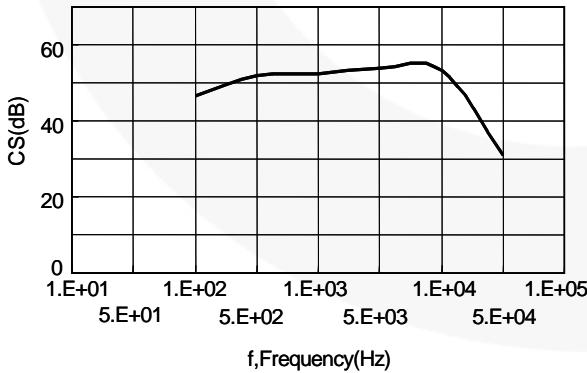


Figure 6. Channel Separation vs. Frequency

Applications

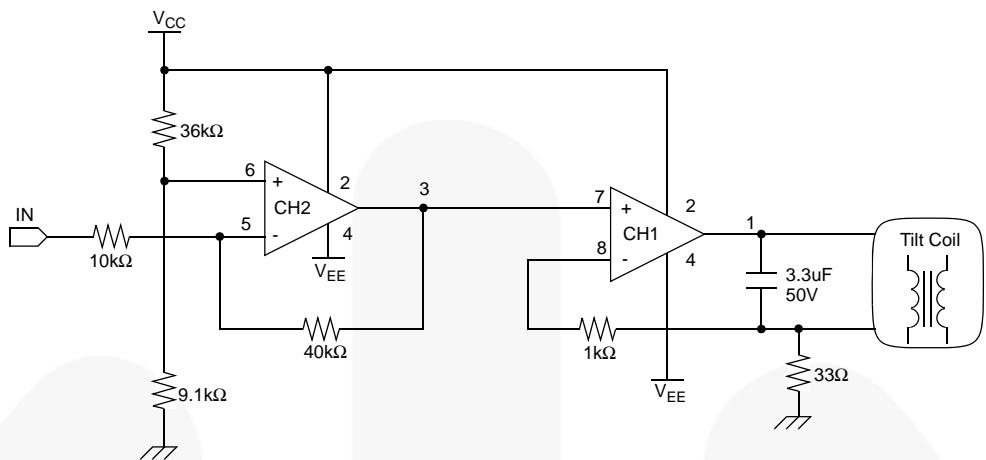
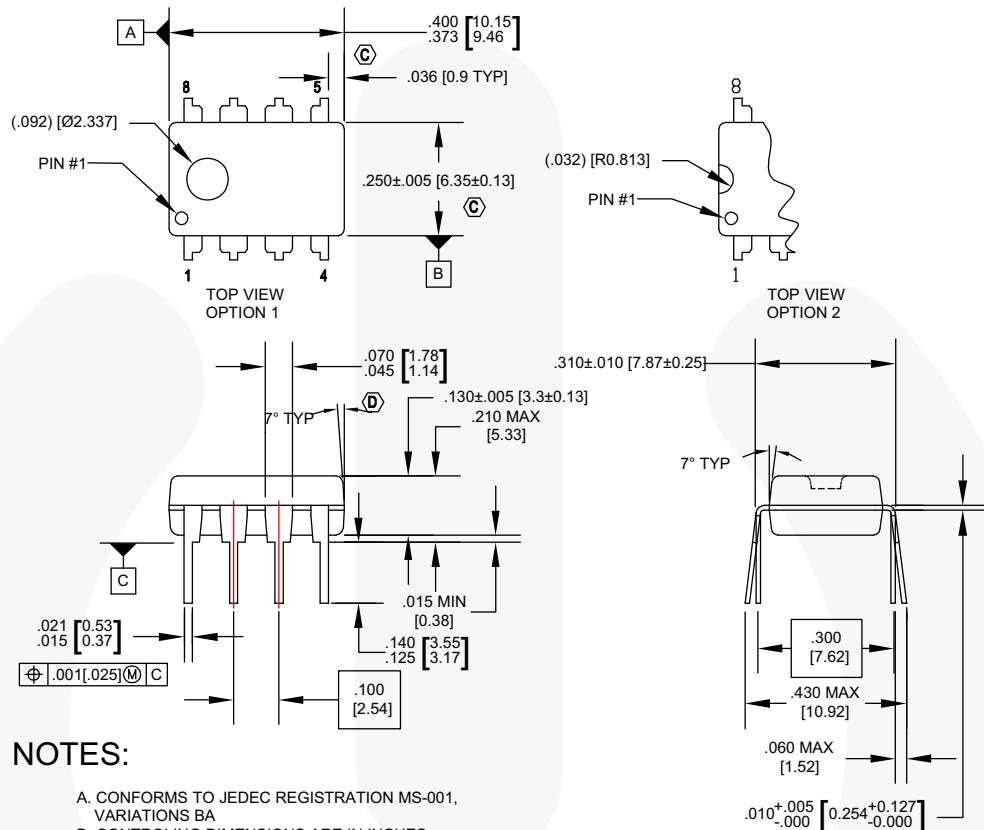


Figure 7. Tilt Coil, Current-Control Circuit in Monitor

Physical Dimensions

MDIP 8L



NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MS-001,
VARIATIONS BA
- B. CONTROLLING DIMENSIONS ARE IN INCHES
REFERENCE DIMENSIONS ARE IN MILLIMETERS
- ⑤ C. DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED
.010 INCHES OR 0.25MM.
- ⑥ D. DOES NOT INCLUDE DAMBAR PROTRUSIONS.
DAMBAR PROTRUSIONS SHALL NOT EXCEED
.010 INCHES OR 0.25MM.
- E. DIMENSIONING AND TOLERANCING
PER ASME Y14.5M-1994.

N08EREVG

Figure 8. 8-LEAD, MDIP, JEDEC MS-001, .300-INCH WIDE

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